

Boost chopper MOSFET Power Module

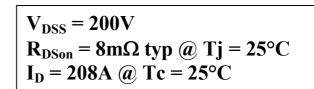
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VBUS SENSE

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Application

- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction

Features

- Power MOS 7[®] MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
 - Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS compliant

Absolute maximum ratings

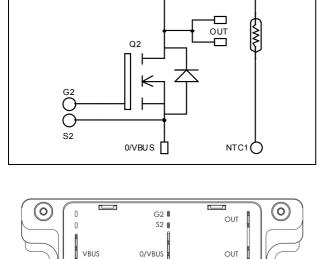
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Symbol	Parameter		Max ratings	Unit
V _{DSS}	Drain - Source Breakdown Voltage		200	V
т	Continuous Drain Commut		208	
I _D	Continuous Drain Current	$T_c = 80^{\circ}C$	155	А
I _{DM}	Pulsed Drain current	purrent		
V _{GS}	Gate - Source Voltage		±30	V
R _{DSon}	Drain - Source ON Resistance		10	mΩ
P _D	Maximum Power Dissipation $T_c = 25^{\circ}C$		781	W
I _{AR}	Avalanche current (repetitive and non repetitive)		100	А
E _{AR}	Repetitive Avalanche Energy		50	mJ
E _{AS}	Single Pulse Avalanche Energy	se Avalanche Energy		111J

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

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All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
I _{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 200V$ $T_j = 25^{\circ}C$			150	μA
		$V_{GS} = 0V, V_{DS} = 160V$ $T_j = 125^{\circ}C$			750	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 104A$		8	10	mΩ
V _{GS(th)}	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 5mA$	3		5	V
I _{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$			±150	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
C _{iss}	Input Capacitance	$V_{GS} = 0V$		14.4		
C _{oss}	Output Capacitance	$V_{\rm DS} = 25 V$		4.66		nF
C _{rss}	Reverse Transfer Capacitance	f=1MHz		0.29		
Qg	Total gate Charge	$V_{GS} = 10V$		280		
Q _{gs}	Gate – Source Charge	$V_{Bus} = 100V$		106		nC
Q_{gd}	Gate – Drain Charge	$I_{\rm D} = 208 {\rm A}$		134		
T _{d(on)}	Turn-on Delay Time	Inductive switching @ 125°C		32		ns
Tr	Rise Time	$V_{GS} = 15V$ $V_{GS} = 122V$		64		
T _{d(off)}	Turn-off Delay Time	$V_{Bus} = 133V$ $I_D = 208A$		88		
$T_{\rm f}$	Fall Time	$R_G = 2.5\Omega$		116		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		1698		T
$\mathrm{E}_{\mathrm{off}}$	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 133V$ $I_D = 208A, R_G = 2.5\Omega$		1858		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		1872		т
$\mathrm{E}_{\mathrm{off}}$	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 133V$ $I_D = 208A, R_G = 2.5\Omega$		1972		μJ

Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V _{RRM}	Maximum Peak Repetitive Reverse Voltage			200			V
I _{RM}	Maximum Reverse Leakage Current	V _R =200V	$T_j = 25^{\circ}C$ $T_j = 125^{\circ}C$			500 750	μΑ
$I_{\rm F}$	DC Forward Current		$T_c = 80^{\circ}C$		180		А
	Diode Forward Voltage	$I_{\rm F} = 180 {\rm A}$			1.1	1.15	
V _F		$I_F = 360A$			1.4		V
		$I_F = 180A$	$T_{j} = 125^{\circ}C$		0.9		
t	Reverse Recovery Time		$T_j = 25^{\circ}C$		31		ns
t _{rr}			$T_j = 125^{\circ}C$		60		115
Q _{rr}	Reverse Recovery Charge	$V_{\rm R} = 133V$ di/dt = 600A/µs	$T_j = 25^{\circ}C$		180		nC
			$T_j = 125^{\circ}C$		750		ne

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Thermal and package characteristics

Symbol	Characteristic
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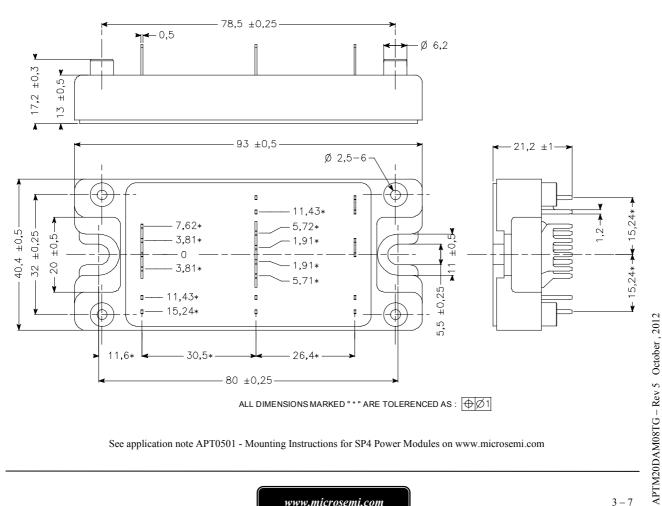
Symbol	Characteristic			Min	Тур	Max	Unit
R _{thJC}	Lunction to Case Thermal Resistance		Transistor			0.16	°C/W
R _{th} JC			Diode			0.32	C/ W
V _{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T _J	Operating junction temperature range		-40		150		
T _{STG}	Storage Temperature Range		-40		125	°C	
T _C	Operating Case Temperature					100	
Torque	Mounting torque	To Heatsink	M5	2.5		4.7	N.m
Wt	Package Weight					160	g

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
B 25/85	$T_{25} = 298.15 \text{ K}$		3952		K

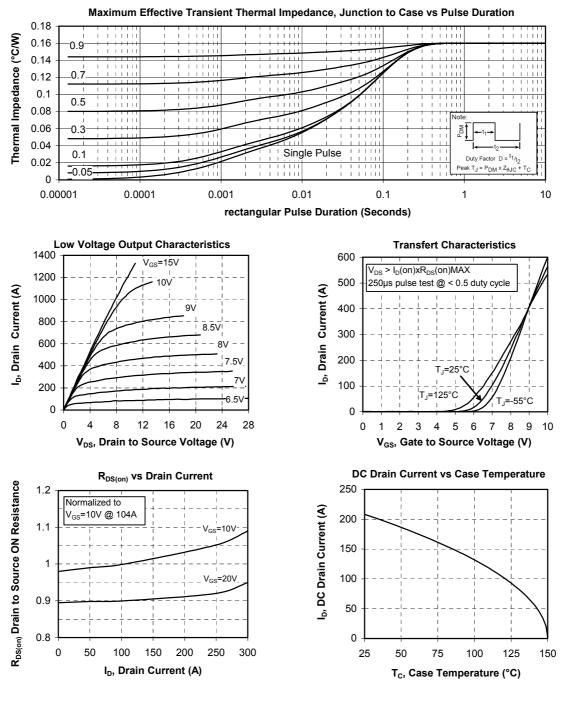
$$R_{T} = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$
 T: Thermistor temperature
R_T: Thermistor value at T

SP4 Package outline (dimensions in mm)



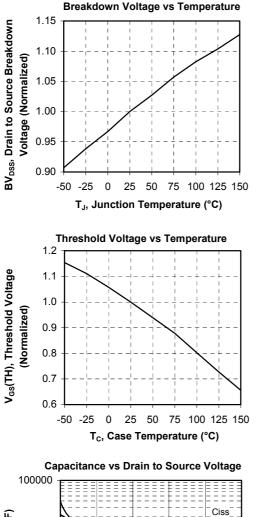


Typical Performance Curve

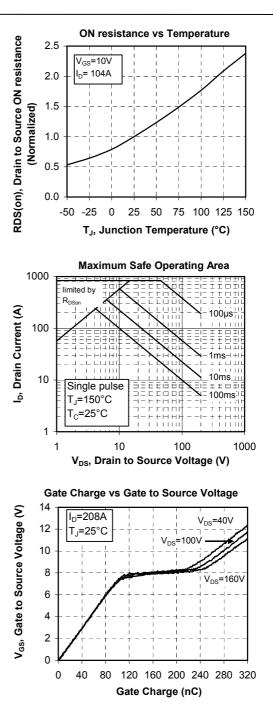


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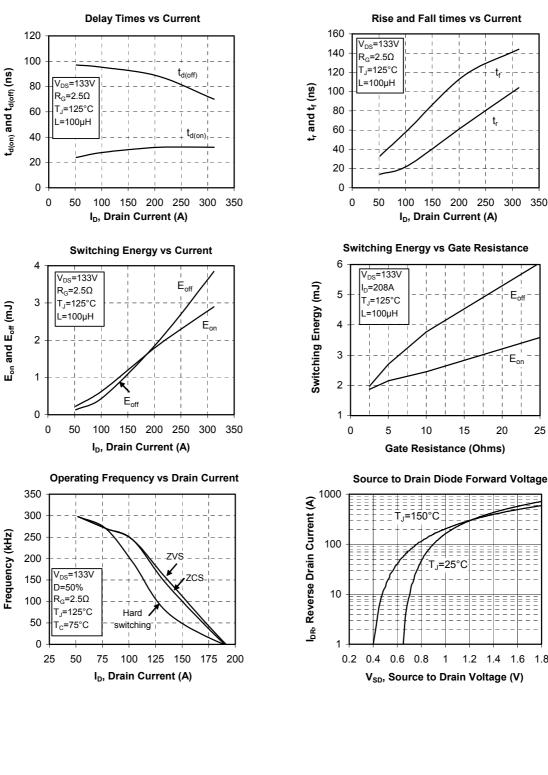


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